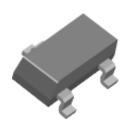
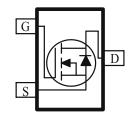
## N-Channel 30V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low  $r_{DS(on)}$  and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

| PRODUCT SUMMARY                                  |                        |     |  |  |  |
|--|------------------------|-----|--|--|--|
| $V_{DS}(V)$ $n_{DS(on)}(\Omega)$ $I_{D}(\Omega)$ |                        |     |  |  |  |
| 30   | $0.058 @V_{CS} = 10 V$ | 2.0 |  |  |  |
|  | $0.082 @V_{CS} = 4.5V$ | 1.7 |  |  |  |

- Low r<sub>DS(on)</sub> provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe SC70-3 saves board space
- Fast switching speed
- High performance trench technology





| ABSOLUTE MAXIMUM RATINGS ( $T_A = 25$ °C UNLESS OTHERWISE NOTED) |  |                                   |            |    |  |  |
|--|--|-----------------------------------|------------|----|--|--|
| Parameter  | Symbol                                 | Maximum                           | Units      |    |  |  |
| Drain-Source Voltage   |  |                                   | 30         | V  |  |  |
| Cate-Source Voltage  | $V_{cs}$                               | ±20                               | V          |    |  |  |
|  | T <sub>A</sub> =25°C                   | Τ_                                | 2.0        |    |  |  |
| Continuous Drain Current <sup>a</sup>                            | $T_A=25^{\circ}C$<br>$T_A=70^{\circ}C$ | 1D                                | 1.7        | A  |  |  |
| Pulsed Drain Current <sup>b</sup>                                | $I_{DM}$                               | ±20                               |            |    |  |  |
| Continuous Source Current (Diode Conduction) <sup>a</sup>        |  | $I_S$                             | 1.6        | A  |  |  |
| D a  | $T_A=25^{\circ}C$                      | D                                 | 0.34       | W  |  |  |
| Power Dissipation <sup>a</sup>                                   | $T_A=25^{\circ}C$<br>$T_A=70^{\circ}C$ | PD                                | 0.22       | VV |  |  |
| Operating Junction and Storage Temperature Range                 |  | T <sub>J</sub> , T <sub>stg</sub> | -55 to 150 | °C |  |  |

| THERMAL RESISTANCE RATINGS               |              |            |       |      |  |  |
|--|--------------|------------|-------|------|--|--|
| Parameter                                | Symbol       | Maximum    | Units |      |  |  |
| M · I · · · a                            | t <= 5 sec   | D          | 100   | °C/W |  |  |
| Maximum Junction-to-Ambient <sup>a</sup> | Steady-State | $R_{THJA}$ | 166   |      |  |  |

1

### Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

| SPECIFICATIONS (T <sub>A</sub> = 25°C UNLESS OTHERWISE NOTED) |                     |   |        |      |      |        |  |
|---|---------------------|---|--------|------|------|--------|--|
| Donomotor   | Samula al           | Task Canditions   | Limits |      |      | TT24   |  |
| Parameter   | Symbol              | <b>Test Conditions</b>  | Min    | Тур  | Max  | Unit   |  |
| Static  |                     |   |        |      |      |        |  |
| Gate-Threshold Voltage  | $V_{GS(th)}$        | $V_{DS} = V_{GS}, I_{D} = 250 \text{ uA}$                                 | 1      |      |      | V      |  |
| Gate-Body Leakage   | $I_{GSS}$           | $V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$                         |        |      | ±100 | nA     |  |
| Zero Gate Voltage Drain Current                               | $I_{ m DSS}$        | $V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$                             |        |      | 1    | uА     |  |
| Zero Gate Voltage Drain Current                               | <sup>1</sup> DSS    | $V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$ |        |      | 10   | uл     |  |
| On-State Drain Current <sup>A</sup>                           | $I_{D(on)}$         | $V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$                             | 10     |      |      | A      |  |
| Drain-Source On-Resistance <sup>A</sup>                       | r <sub>DS(on)</sub> | $V_{GS} = 10 \text{ V}, I_D = 2.0 \text{ A}$                              |        |      | 58   | mΩ     |  |
| Diani-Source On-Resistance                                    |                     | $V_{GS} = 4.5 \text{ V}, I_D = 1.7 \text{ A}$                             |        |      | 82   | 1115.2 |  |
| Forward Tranconductance <sup>A</sup>                          | $g_{ m fs}$         | $V_{DS} = 10 \text{ V}, I_{D} = 2.0 \text{ A}$                            |        | 11.3 |      | S      |  |
| Diode Forward Voltage   | $V_{\mathrm{SD}}$   | $I_S = 1.6 \text{ A}, V_{GS} = 0 \text{ V}$                               |        | 0.75 |      | V      |  |
| Dynamic <sup>b</sup>  |                     |   |        |      |      |        |  |
| Total Gate Charge   | $Q_{g}$             |   |        | 7.5  |      |        |  |
| Gate-Source Charge  | $Q_{gs}$            | $V_{DS} = 10 \text{ V}, V_{GS} = 5 \text{ V}, I_{D} = 2.0 \text{ A}$      |        | 0.6  |      | пC     |  |
| Gate-Drain Charge   | $Q_{gd}$            |   |        | 1.0  |      |        |  |
| Turn-On Delay Time  | $t_{d(on)}$         |   |        | 8    |      |        |  |
| Rise Time   | t <sub>r</sub>      | $V_{DD} = 10 \text{ V}, R_L = 15 \Omega, I_D = 1 \text{ A},$              |        | 24   |      |        |  |
| Turn-Off Delay Time   | t <sub>d(off)</sub> | $V_{GEN} = 4.5 \text{ V}$   |        | 35   |      | ns     |  |
| Fall-Time   | $t_{\mathrm{f}}$    |   |        | 10   |      |        |  |

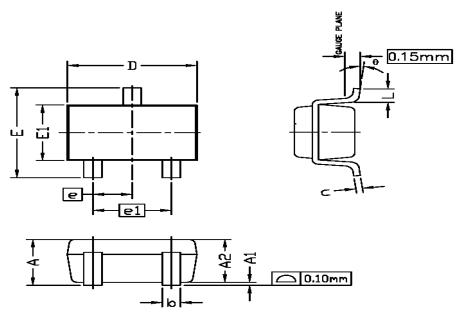
#### Notes

- a. Pulse test:  $PW \le 300us duty cycle \le 2\%$ .
- b. Guaranteed by design, not subject to production testing.

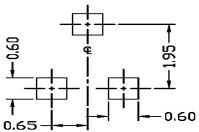
Analog Power (APL) reserves the right to make changes without further notice to any products herein. APL makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does APL assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in APL data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. APL does not convey any license under its patent rights nor the rights of others. APL products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the APL product could create a situation where personal injury or death may occur. Should Buyer purchase or use APL products for any such unintended or unauthorized application, Buyer shall indemnify and hold APL and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that APL was negligent regarding the design or manufacture of the part. APL is an Equal Opportunity/Affirmative Action Employer.

# Package Information

SC70 PACKAGE OUTLINE



### RECOMMENDED LAND PATTERN



| TI | N | IT: | - | ım |
|----|---|-----|---|----|
|    |   |     |   |    |

| SYMBOLS    | DIMENSIONS IN MILLIMETERS |          |      | DIMENSIONS IN INCHES |       |       |
|------------|---------------------------|----------|------|----------------------|-------|-------|
| SIMBULS    | MIN                       | NOM      | MAX  | MIN                  | NOM   | MAX   |
| Α          |                           |          | 1.10 |                      |       | 0.043 |
| A1         | 0.00                      |          | 0.10 | 0.00                 |       | 0.004 |
| A2         | 0.7                       | 0.9      | 1.00 | 0.028                | 0.035 | 0.039 |
| ь          | 0.15                      |          | 0.30 | 0.006                |       | 0.012 |
| c          | 0.08                      |          | 0.22 | 0.003                |       | 0.009 |
| D          | 1.85                      | 2.10     | 2,15 | 0.073                | 0.083 | 0.085 |
| E          | 1.80                      | 2.30     | 2.40 | 0.071                | 0.091 | 0.094 |
| e          |                           | 0.65 BSC |      | 0.026 BSC            |       |       |
| el         |                           | 1.30 BSC |      | 0.051 BSC            |       |       |
| <b>E</b> 1 | 1.1                       | 1.30     | 1.4  | 0.043                | 0.051 | 0.055 |
| L          | 0.26                      | 0.36     | 0.46 | 0.010                | 0.014 | 0.018 |
| θ          | 0°                        | 4°       | 80   | O°                   | 4°    | 80    |

### NOTE

- 1. ALL DIMENSIONS ARE IN MILLMETERS.
- 2. DIMENSIONS ARE INCLUSIVE OF PLATING.
- 3. PACKAGE BODY SIZES EXCLUDE MOLD FLASH AND GATE BURRS.
  MOLD FLASH AT THE NON-LEAD SIDES SHOULD BE LESS THAN 3 MILS EACH.
- DIE IS FACING UP FOR MOLD AND FACING DOWN FOR TRIM/FORM. ie: REVERSE TRIM/FORM.
- 5. DIMENSION L IS MEASURED IN GAUGE PLANE.
- 6. CONTROLLING DIMENSION IS MILLIMETER.
  - CONVERTED INCH DIMENSIONS ARE NOT NECESSARILY EXACT.